

UNISONIC TECHNOLOGIES CO., LTD

BTA40 Preliminary TRIAC

40A STANDARD TRIAC

■ DESCRIPTION

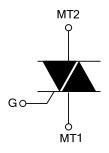
The UTC **BTA40** is a 40A standard triac, it uses UTC's advanced technology to provide customers with low thermal resistance with clip bonding and high commutation capability, etc.

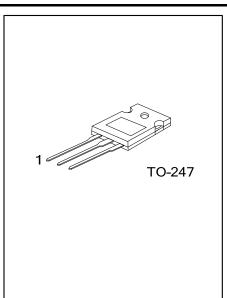
The UTC **BTA40** is suitable for general purpose AC switching, heating regulation and on/off function in static relays, etc.

■ FEATURES

- * Low thermal resistance with clip bonding
- * High current capability
- * High commutation capability

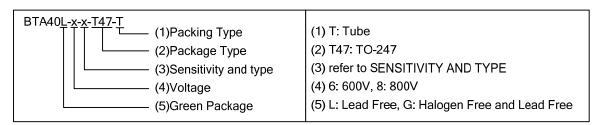
SYMBOL





ORDERING INFORMATION

Ordering Number		Dookooo	Pin Assignment			Da alsia s	
Lead Free	Halogen Free	Package	1	2	3	Packing	
BTA40L-x-x-T47-T	BTA40G-x-x-T47-T	TO-247	MT1	MT2	G	Tube	

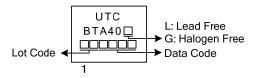


■ SENSITIVITY AND TYPE

PART NUMBER	VOL1	AGE	OF MOITIV/ITV	TYPE	
PART NUMBER	600V	800V	SENSITIVITY	ITPE	
В	0	0	50mA	STANDARD	

⊚: Available

MARKING



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■ ABSOLUTE MAXIMUM RATINGS

PARAMETER			RATINGS	UNIT
On-State RMS Current (Full Sine Wave)	T _C =80°C	I _{T(RMS)}	40	Α
Non Repetitive Surge Peak On-State F=50Hz, t=2			400	Α
Current (Full Cycle, T _J initial=25°C)	F=60Hz, t=16.7ms	I _{TSM}	420	Α
I ² t Value for Fusing	t _p =10ms	l ² t	1000	A ² s
Critical Rate of Rise of On-State Current: $I_G=2xI_{GT}$, $t_r \le 100$ ns	F=120Hz, T _J =125°C	dl/dt	50	A/μs
Non Repetitive Surge Peak Off-State Voltage	t _p =10ms, T _J =25°C	V_{DSM}/V_{RSM}	V _{DSM} /V _{RSM} +100	V
Peak Gate Current	t _p =20μs, T _J =125°C	I_{GM}	8	Α
Average Gate Power Dissipation	T _J =125°C	$P_{G(AV)}$	1	W
Operating Junction Temperature		T_J	-40~+125	°C
Storage Junction Temperature	_	T _{STG}	-40~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ DEVICE SUMMARY

PARAMETER	SYMBOL	RATINGS	UNIT
On-State RMS Current	I _{T(RMS)}	40	Α
Repetitive Peak Off-State Voltage	V_{DRM}/V_{RRM}	600	٧
Triggering Gate Current	I _{GT}	50	mA

■ THERMAL RESISTANCES

PARAMETER		RATINGS	UNIT	
Junction to Ambient	θ_{JA}	40	°C/W	
Junction to Case (AC)	θ_{JC}	1.5	°C/W	

■ ELECTRICAL CHARACTERISTICS (T_J=25 °C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Gate Trigger Current (Note 1)	I _{GT}		1-11-111			50	mA
		V_D =12V, R_L =33 Ω	IV			100	mA
Gate Trigger Voltage	V_{GT}		ALL			1.3	V
Gate Non-Trigger Voltage	V_{GD}	$V_D=V_{DRM}, R_L=3.3k\Omega,$	ALL	0.2			V
Gate Non-Trigger Voltage	V GD	T _J =125°C	/ \	0.2			v
Holding Current (Note 2)	I _H	I _T =500mA				80	mA
Latching Current	I _L I _G =1.2I _{GT}	1 -4 01	I-III-IV			70	mA
		IG=1.ZIGT	II			160	mA
Critical Rate of Rise of Off-State	dV/dt	V _D =67%V _{DRM} , Gate Open, T _J =125		500			\//uo
Voltage (Note 2)	dv/dt V _D =67% V _{DRM} , Gate Open, 1		J-125 C	500			V/µs
Critical Rate of Rise of Off-State	(dV/dt)c	(dl/dt)c=20A/ms, T _J =125°C		10			V/µs
Voltage at Commutation (Note 2)	(uv/ut)c	(u//ut/)c-20/4/1115, 1J-125 C		10			ν/μ5

STATIC CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Peak On-State Voltage (Note 2)	V_{TM}	I_{TM} =60A, t_p =380 μ s, T_J =25 $^{\circ}$ C			1.55	V
Threshold Voltage (Note 2)	V_{TO}	T _J =125°C			0.85	V
Dynamic Resistance (Note 2)	R_D	T _J =125°C			10	mΩ
Depatitive Deals Off State Surrent	I _{DRM}	V _{DRM} =V _{RRM} , T _J =25°C			5	μΑ
Repetitive Peak Off-State Current	I_{RRM}	V _{DRM} =V _{RRM} , T _J =125°C			5	mA

Notes: 1. Minimum I_{GT} is guaranted at 5% of I_{GT} max.

2. For both polarities of MT2 referenced to MT1.

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